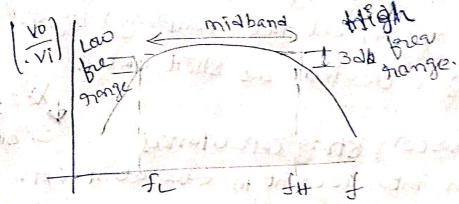
unit -II Freathency response

All philips gain factors are functions of signal bearing

7 These include voltage, current, brans conductance and Grans resistance.



The curve drawn between frauency & gain factor is alled frevuency response curve.

The frequency nanges are divided as:

- low breaking f<fL 20H3 <f < 20KH3
- High breauonry f 7 ft ft 720 KH3
- Medium Brawny.

Frequency roungs

13 Inthis region coupling and by pass capacitors must beinduded in the equivalent cut and in the

amplification factor caucitions

The Stray and transiter capacitances are troated as mon okti-

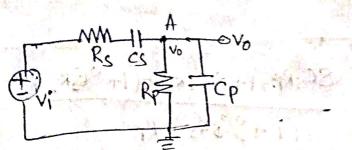
-> In Low Breamnies mange, fell, the gain I as fre & because of couplings by pass capacits effects.

In tuis gange all the Stray & parasitic capacito, -High browning Rong c -> due to their capacitances the gain decreases as providency increase. 7 Inthis namge we use thigh freaking equivalent > In this neglariall the coupling & 134 parts capacitary oute going to treated as short cits. Sh & tckb. The transists of Btray capacitaness are taken into account in Equivalent CET. -) due to Projunction (between colleto, base and conitter) CA & CTT midband Range: - 110 coupling 4 bypass capacitors are breated as short cxt) stray and transisted capacitances are treated as open ckts.) so Intuix gange no capacitacy in the equivalent

ickt.

Taglic Boll Disconnic

short cxt and open cxt time constant



cs is the coupling capacitor

-cp.is the load capacitos and is in parallel with

the output ant ground.

- Applying RCL at output node

I due to cs at low frequencies the

gain is going to be reduced

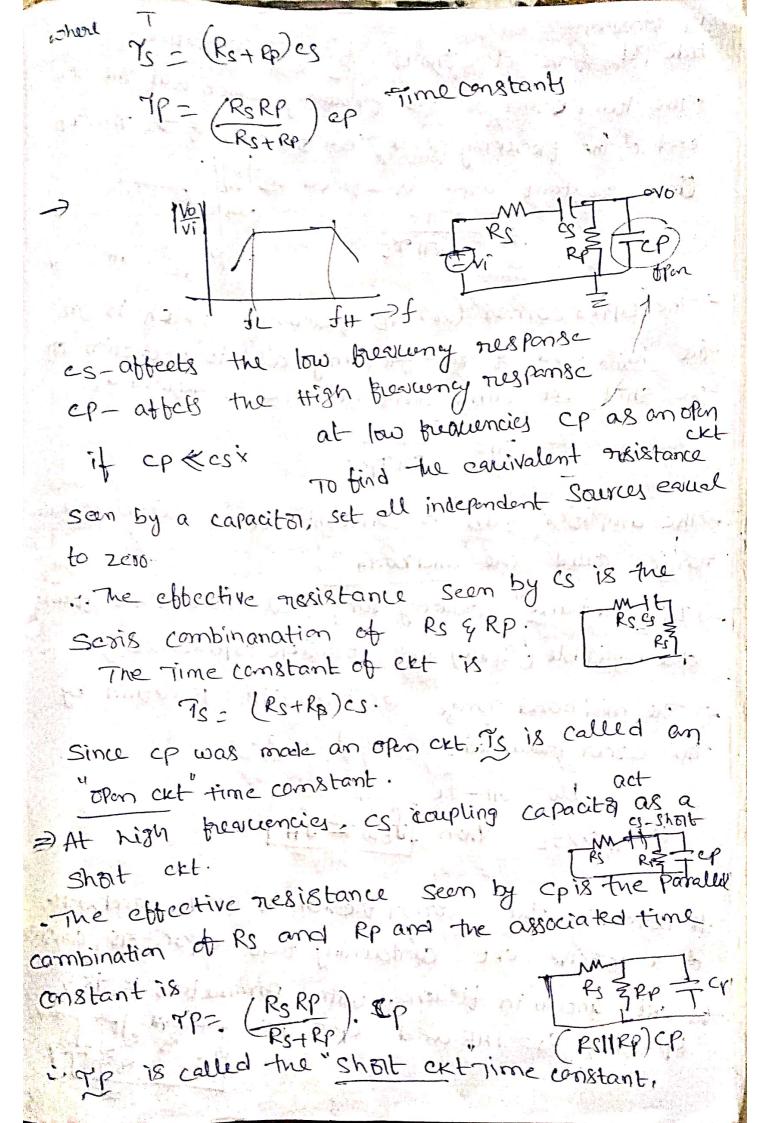
-> due to cp at High frequencies the gain is

going to be reduced. at mid the the stray, paracitic apacitances are appear 150, gain maintains Applying constant. -> Applying

KCL at nodeA ie) output node

separate vo q vi terms, to get the transfer function

Vo. so, tue equation be come



Let tonsider

Side 196t of the retare principles function inspirituale.

The break termer (an) sub-fraction of the object end of the fraction of the object. It is tenetism of the object time constant and 13 defined as 1911.

Let 1975

The upper commer (or) 3dB framening which is at the high and of the framening scale is a function of the Shift cet time constant and is orifined as

न्स= हार्गः

The amplifier gain is constant over a wide frence, hange, called tree mid bond".

In "mid band" frewhency range all caracitances offects one regligible (Stray and parasitic capacitances)

The mid band range (or) bandwidth is defined by the corner fremencies from d for as

Bw= fH-fL 18. fH>7fL then [fBw=fH]

Determine the corner treasconcies and bondwidth of a passive Ckt containing two capacitors, consister ckt ghown in tisuere, with parameters Rs-1k/4 RP=0KL, Cs=1HF and CP=3PF. The RS est Top

$$75 = (R_{5} + R_{P}) c_{5} = (R_{5}^{3} + 10 \times 10^{3})(10^{6}) = 1.1 \times 10^{2} c_{5}$$

$$77 = (R_{5} + R_{P}) c_{7} = \frac{10^{3} + 10 \times 10^{3}}{10^{3} + 10 \times 10^{3}}(3 \times 10^{2}) = 2.73 \times 10^{9} c_{5}$$

$$51 = \frac{1}{27175} c_{5} = \frac{1}{27175} c_{5} = 14.5 + 13$$

$$51 = \frac{1}{27175} c_{5} = \frac{1}{27175} c_{5} = 14.5 + 13$$

$$51 = \frac{1}{27175} c_{5} = \frac{1}{27175} c_{5} = 14.5 + 13$$

$$580 = \frac{1}{27175} c_{5} = \frac{1}{27175$$

- upto now is steady state sinuspidal frencency nesponse, we for sinuspidal inputs.

To some cases, we may need to amplify other tuan sinuspidal sisnal also, le pulse, souvare mans tar signals. je digital signals.

) In tuese cases, we need to coinsider the time

nessanse of output signals. Severil toad coupling caracita

consider ckt

THE ERP

The voltage transfer bunction of above cet

1+ SCRS-IRP)CS

Inthe input voltage is a step function $V_1(s)=1/s$ be series coupling capacitis ext. Then output voltage $V_0(s)=1/s$ Ps & EP

Taking "Invesse Laptace transfortunction, then

If we apply pulse input voltage, to above ext the voltage applied to load ckt 18 slowly decreases. In the input voltage is a step function $V_1(S)=1/S$. be series coupling capacitistickt. Then output voltage $V_1(S)=1/S$. Vo $V_2(S)=1/S$. VO(S) = K2 (Sto) = = (RS+RP) (SCRS+RP) (S) VO(5)= K2 (SP2) if VIS)= 1/6 = k2 (1/2) VOCS) = k2 (8/2) x 1 1+872 S. = K2 (32) B = K2 (3+1/40) Taking Invesse Laplace transfertunction, then VOCDIT V6(3)= K2 e-t/12

If we apply pulse input voltage, to above ckt the voltage applied to load ckt 18 slowly decreases.

we can rearrange the terms and write the function as

$$T(s) = K_1 \left(\frac{1}{1+s\tau_1}\right) \tag{7.2(b)}$$

where
$$\tau_1$$
 is a **time constant**. Other transfer functions may be written as
$$T(s) = K_2 \left(\frac{s\tau_2}{1 + s\tau_2} \right)$$
where τ_2 is also a time constant. In most cases, we will write the transfer func-

where τ_2 is also a time constant. In most cases, we will write the transfer func-vious panel and the time again. tions in terms of the time constants.

To introduce the frequency response analysis of transistor circuits, we will examine the circuits shown in Figures 7.2 and 7.3. The voltage transfer function for the circuit in Figure 7.2 can be expressed in a voltage divider format, as follows:

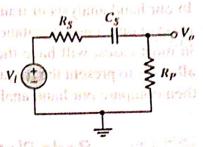


Figure 7.2 Series coupling capacitor circuit

$$\frac{V_o(s)}{V_i(s)} = \frac{R_P}{R_S + R_P + \frac{1}{sC_S}}$$
 and the first section of the first sect

The elements R_S and C_S are in series between the input and output signals, and the element R_P is in parallel with the output signal. Equation (7.3) can be written in the form

$$\frac{V_{\rho}(s)}{V_{i}(s)} = \frac{V_{\rho}(s)}{1 + s(R_{S} + R_{P})C_{S}} = \frac{V_{i}(s)}{1 + s(R_{S} + R_{P})C_{S}} = \frac{V_{i}(s)}$$

which can be rearranged and written as sention out to shortegain a

$$\frac{V_o(s)}{V_i(s)} = \left(\frac{R_P}{R_S + R_P}\right) \left[\frac{s(R_S + R_P)C_S}{1 + s(R_S + R_P)C_S}\right] = K_2 \left(\frac{s\tau}{1 + s\tau}\right)$$
(7.5) Figure 7.3 Parallel load capacitor circuit

In this equation, the time constant is

$$\tau = (R_S + R_P)C_S$$

necessing frequency, and reach a consum value and relatively high frequency. In Writing a Kirchhoff current law (KCL) equation at the output node, we can determine the voltage trans fer function for the circuit shown in Figure 7.3, as follows:

$$\frac{V_o - V_i}{R_S} + \frac{V_o}{R_P} + \frac{V_o}{(1/sC_P)} = 0$$
That is the standard problem of the problem of the standard problem

Wit therefore earpeat the transparede of the teams for thusing to start a

In this case, the element R_S is in series between the input and output signals, and the elements R_P and C_P and C_P and C_P are in parallel with the output signal. Rearranging the terms in Equation (7.6) produces

$$\frac{V_o(s)}{V_i(s)} = \left(\frac{R_P}{R_S + R_P}\right) \left[\frac{1}{1 + s\left(\frac{R_S R_P}{R_S + R_P}\right) C_P}\right]$$
(7.76)

476 Part 1 Semiconductor Devices and Basic Applications

or

$$\frac{V_o(s)}{V_i(s)} = \left(\frac{R_P}{R_S + R_P}\right) \left[\frac{1}{1 + s(R_S || R_P)C_P}\right]$$

(1.7(1

In Equation (7.7(b)), the time constant is

$$\tau = (R_S || R_P) C_P$$

722 First-Order Functions

Consider, now, the circuit shown in Figure 7.18, which is a repeat of Figure 7.3. In this case, the capac-Cr may represent the input capacitance of an amplifier. The transfer function was given in Equation

$$\frac{V_o(s)}{V_i(s)} = \left(\frac{R_P}{R_S + R_P}\right) \cdot \left[\frac{1}{1 + s \left(R_P \parallel R_S\right) C_P}\right] \tag{7.26}$$

$$\frac{V_{\sigma}(s)}{V_{\sigma}(s)} = K_1 \left(\frac{1}{1 + s \tau_1} \right) \tag{7.27}$$

where the time constant is $\tau_1 = (R_P || R_S)C_P$.

Again, if the input signal is a step function, then $V_i(s) = 1/s$. The output voltage can then be written as

$$V_{\theta}(s) = \frac{K_1}{s} \left(\frac{1}{1 + s\tau_1} \right) = \frac{K_1}{s} \left(\frac{1/\tau_1}{s + 1/\tau_1} \right)$$
 (7.28)

Taking the inverse Laplace transform, we find the output voltage time response as

$$\mathbf{v}_O(t) = K_i(1 - e^{-t/\tau_1})$$
 (7.29)

If we are trying to amplify an input voltage pulse, we need to ensure that the time constant τ_1 is short compared to the pulse width T, so that the signal $v_O(t)$ reaches a steady-state value. The output voltage is shown in Figure 7.19 for a square wave input signal. A short time constant implies a very small capacitor C_P as an input capacitance to an amplifier.

In this case, if the cutoff frequency of the transfer function is f_{3-dB} = $1/2\pi \tau_1 = 10$ MHz, then the time constant is $\tau_1 = 15.9$ ns.

Figure 7.20 summarizes the steady-state output responses for square wave input signals of the two circuits we've just been considering. Figure 7.20(a) shows the steady-state output response of the circuit in Figure 7.16 (coupling capacitor) for a long time constant, and Figure 7.20(b) shows the steady-state output response of the circuit in Figure 7.18 (load capacitor) for a short time constant.

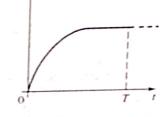


Figure 7.19 Output response of circuit in Figure 7.18 for a square-wave input signal and for a short time constant

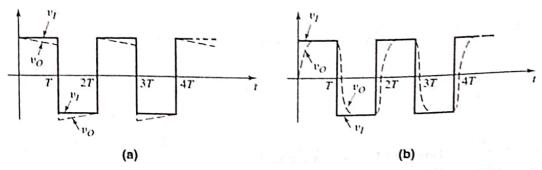


Figure 7.20 Steady-state output response for a square-wave input response for (a) circuit in Figure 7.16 (coupling capacitor) and a large time constant, and (b) circuit in Figure 7.18 (load capacitor) and a short time constant

7.3 FREQUENCY RESPONSE: TRANSISTOR AMPLIFIERS WITH CIRCUIT CAPACITORS

Objective: • Analyze the frequency response of transistor circuits with capacitors.

In this section, we will analyze the basic single-stage amplifier that includes circuit capacitors. Three types of capacitors will be considered: coupling capacitor, load capacitor, and bypass capacitor. In our hand analysis, we will consider each type of capacitor individually and determine its frequency response. In the last part of this section, we will consider the effect of multiple capacitors using a PSpice analysis.

The frequency response of multistage circuits will be considered in Chapter 12 when the stability of amplifiers is considered.

7.3.1 Coupling Capacitor Effects

Input Coupling Capacitor: Common-Emitter Circuit

Figure 7.21(a) shows a bipolar common-emitter circuit with a coupling capacitor. Figure 7.21(b) shows the corresponding small-signal equivalent circuit, with the transistor small-signal output resistance r_o assumed to

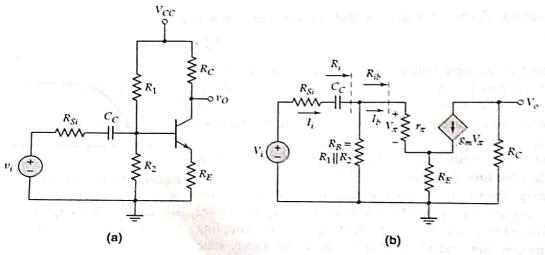


Figure 7.21 (a) Common-emitter circuit with coupling capacitor and (b) small-signal equivalent circuit

be infinite. This assumption is valid since $r_0 \gg R_C$ and $r_0 \gg R_E$ in most cases. Initially, we will use a current-voltage analysis to determine the frequency response of the circuit. Then, we will use the equivalent time constant technique.

From the analysis in the previous section, we note that this circuit is a high-pass network. At high frequencies, the capacitor C_C acts as a short circuit, and the input signal is coupled through the transistor to the output. At low frequencies, the impedance of C_C becomes large and the output approaches zero.

Current-Voltage Analysis: The input current can be written as

$$I_{i} = \frac{V_{i}}{R_{Si} + \frac{1}{sC_{C}} + R_{i}} \tag{7.30}$$

where the input resistance R_i is given by

$$R_i = R_B \| [r_\pi + (1+\beta)R_E] = R_B \| R_{ib}$$
 (7.31)

In writing Equation (7.31), we used the resistance reflection rule given in Chapter 6. To determine the input resistance to the base of the transistor, we multiplied the emitter resistance by the factor $(1 + \beta)$.

Using a current divider, we determine the base current to be

$$I_b = \left(\frac{R_B}{R_B + R_{ib}}\right) I_i \tag{7.32}$$

and then

$$V_{\pi} = I_b r_{\pi} \tag{7.33}$$

The output voltage is given by

$$V_o = -g_m V_\pi R_C \tag{7.34}$$

Combining Equations (7.30) through (7.34) produces

$$V_{o} = -g_{m}R_{C}(I_{b}r_{\pi}) = -g_{m}r_{\pi}R_{C}\left(\frac{R_{B}}{R_{B} + R_{ib}}\right)I_{i}$$

$$= -g_{m}r_{\pi}R_{C}\left(\frac{R_{B}}{R_{B} + R_{ib}}\right)\left(\frac{V_{i}}{R_{Si} + \frac{1}{sC_{C}} + R_{i}}\right)$$
(7.35)

Therefore, the small-signal voltage gain is

Therefore, the small-signal voltage gain is
$$A_v(s) = \frac{V_o(s)}{V_i(s)} = -g_m r_\pi R_C \left(\frac{R_B}{R_B + R_{ib}}\right) \left(\frac{sC_C}{1 + s(R_{Si} + R_i)C_C}\right) \tag{7.36}$$

which can be written in the form

$$A_{v}(s) = \frac{V_{o}(s)}{V_{i}(s)} = \frac{-g_{m}r_{\pi}R_{C}}{(R_{Si} + R_{i})} \left(\frac{R_{B}}{R_{B} + R_{ib}}\right) \left(\frac{s\tau_{S}}{1 + s\tau_{S}}\right)$$

$$(7.37)$$

where the time constant is

$$\tau_S = (R_{Si} + R_i)C_C \tag{7.38}$$

The form of the voltage transfer function as given in Equation (7.37) is the same as that of Equation (7.5), for the coupling capacitor circuit in Figure 7.2. The Bode plot is therefore similar to that shown in Figure 7.5. The corner frequency is

$$f_L = \frac{1}{2\pi \tau_S} = \frac{1}{2\pi (R_{Si} + R_i)C_C}$$
the maximum (7.39)

and the maximum magnitude, in decibels, is

$$|A_{r}(\max)|_{dB} = 20 \log_{10} \left(\frac{g_{m} r_{\pi} R_{C}}{R_{Si} + R_{i}} \right) \left(\frac{R_{B}}{R_{B} + R_{ib}} \right)$$
(7.40)

EXAMPLE 7.3

Objective: Calculate the corner frequency and maximum gain of a bipolar common-emitter circuit with a coupling capacitor.

For the circuit shown in Figure 7.21, the parameters are: $R_1 = 51.2 \text{ k}\Omega$, $R_2 = 9.6 \text{ k}\Omega$, $R_C = 2 \text{ k}\Omega$, $R_E = 0.4 \text{ k}\Omega$, $R_{Si} = 0.1 \text{ k}\Omega$, $C_C = 1 \mu\text{F}$, and $V_{CC} = 10 \text{ V}$. The transistor parameters are: $V_{BE}(\text{on}) = 0.7 \text{ V}$, $\beta = 100$, and $V_A = \infty$.

Solution: From a dc analysis, the quiescent collector current is $I_{CQ} = 1.81$ mA. The transconductance is therefore

$$g_m = \frac{I_{CQ}}{V_T} = \frac{1.81}{0.026} = 69.6 \text{ mA/V}$$

and the diffusion resistance is

$$r_{\pi} = \frac{\beta V_T}{I_{CQ}} = \frac{(100)(0.026)}{1.81} = 1.44 \,\mathrm{k}\Omega$$

The input resistance is

$$R_i = R_1 \|R_2\| [r_\pi + (1+\beta)R_E]$$

= 51.2 \|9.6\| [1.44 + (101)(0.4)] = 6.77 k\Omega

and the time constant is therefore

$$\tau_S = (R_{Si} + R_i)C_C = (0.1 \times 10^3 + 6.77 \times 10^3)(1 \times 10^{-6}) = 6.87 \times 10^{-3} \text{ s}$$

or

$$\tau_S = 6.87 \, \text{ms}$$

The corner frequency is

$$f_L = \frac{1}{2\pi \tau_S} = \frac{1}{2\pi (6.87 \times 10^{-3})} = 23.2 \,\text{Hz}$$

Finally, the maximum voltage gain magnitude is

$$|A_v|_{\text{max}} = \frac{g_m r_\pi R_C}{(R_{Si} + R_i)} \left(\frac{R_B}{R_B + R_{ib}} \right)$$

where

$$R_{ib} = r_{\pi} + (1+\beta)R_E = 1.44 + (101)(0.4) = 41.8 \text{ k}\Omega$$

Therefore,

$$|A_v|_{\text{max}} = \frac{(69.6)(1.44)(2)}{(0.1 + 6.775)} \left(\frac{8.084}{8.084 + 41.84}\right) = 4.72$$